



DMTH6010LPDQ

60V 175°C DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _C = +25°C
60V	11mΩ @ V _{GS} = 10V	47.6A
000	16mΩ @ V _{GS} = 4.5V	39.5A

Description and Applications

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

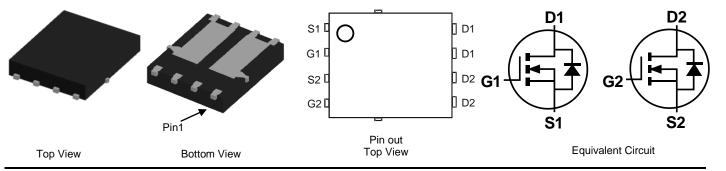
- **Engine Management Systems**
- **Body Control Electronics**
- **DCDC** Converters

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching ensures more reliable and robust end application
- **High Conversion Efficiency**
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: PowerDI5060-8 (Type C)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 5)

	Part Number	Case	Packaging			
	DMTH6010LPDQ-13	PowerDI5060-8 (Type C)	2,500/Tape & Reel			
Notes:	Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.					

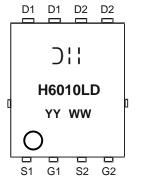
purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



];; = Manufacturer's Marking H6010LD = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 16 = 2016) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	60	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Note 7)	T _C = +25°C T _C = +100°C	Ι _D	47.6 33.7	А
Continuous Drain Current (Note 6)	T _A = +25°C T _A = +70°C	I _D	13.1 10.9	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	90	A	
Maximum Continuous Body Diode Forward Current (Note 7)	ls	31	A	
Avalanche Current, L = 0.1mH	I _{AS}	20	A	
Avalanche Energy, L = 0.1mH	E _{AS}	20	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	53	°C/W
Total Power Dissipation (Note 7)	PD	37.5	W
Thermal Resistance, Junction to Case (Note 7)	R _{0JC}	4	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symphol	Min	Turn	Max	Unit	Toot Condition	
	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)			1	1			
Drain-Source Breakdown Voltage	BV _{DSS}	60			V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	—	—	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	Igss		—	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	1	—	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Passa	—	8.5	11	mΩ	$V_{GS} = 10V, I_D = 20A$	
	R _{DS(ON)}	_	10.9	16	11152	$V_{GS} = 4.5V, I_D = 20A$	
Diode Forward Voltage	V _{SD}	_	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 9)			•	•			
Input Capacitance	C _{iss}	_	2615	—	pF	V _{DS} = 30V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	1415	_	pF		
Reverse Transfer Capacitance	Crss		58	_	pF		
Gate Resistance	Rg	_	0.67	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	20.3	_	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	_	40.2	—	nC		
Gate-Source Charge	Q _{gs}	_	5.9	_	nC	$V_{\rm DS} = 30V, I_{\rm D} = 20A$	
Gate-Drain Charge	Q _{gd}	_	9.3	_	nC	1	
Turn-On Delay Time	t _{D(ON)}	_	5.7	_	ns		
Turn-On Rise Time	t _R	_	8.8	—	ns	$V_{DD} = 30V, V_{GS} = 10V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	20.8	—	ns	$I_D = 20A, R_G = 3\Omega$	
Turn-Off Fall Time	t _F	_	7.4	—	ns	1	
Body Diode Reverse Recovery Time	t _{RR}	_	34.5	—	ns		
Body Diode Reverse Recovery Charge	Q _{RR}		37.5	—	nC	I _F = 20A, di/dt = 100A/µs	

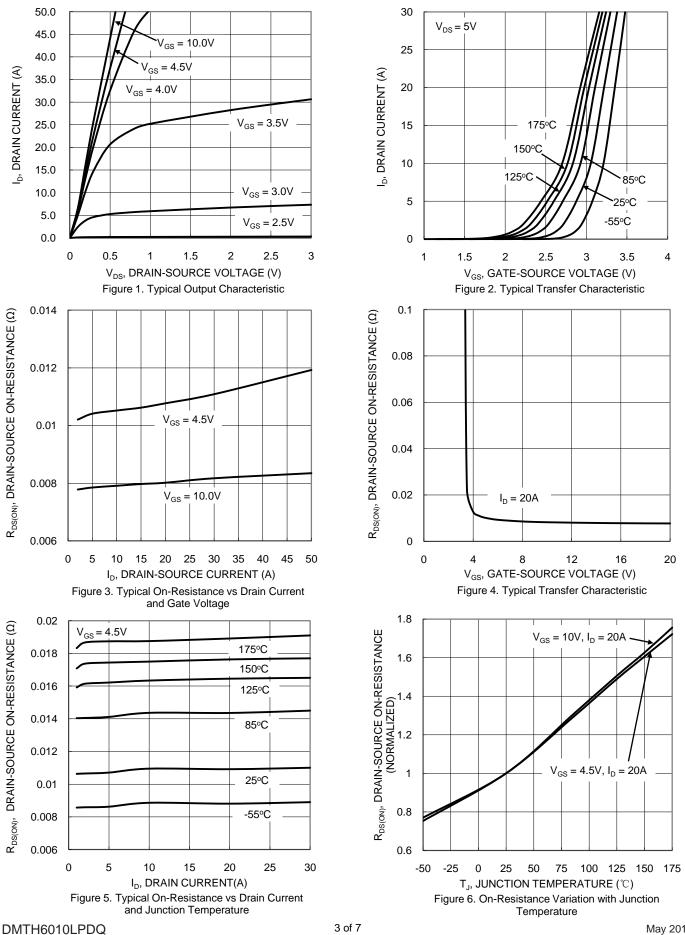
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. Notes:

7. Thermal resistance from junction to soldering point (on the exposed drain pad).

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



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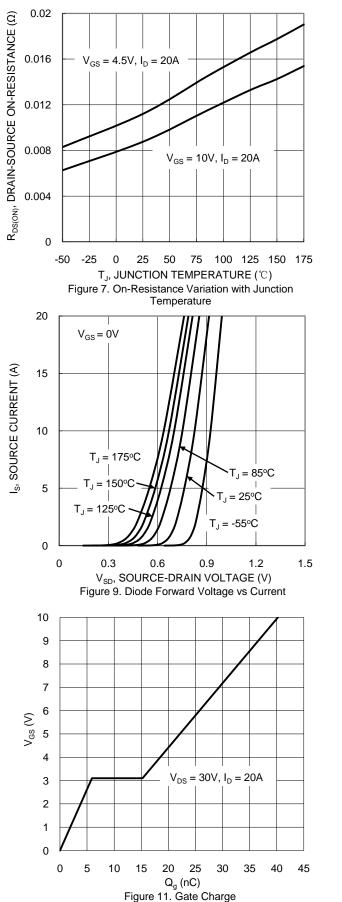


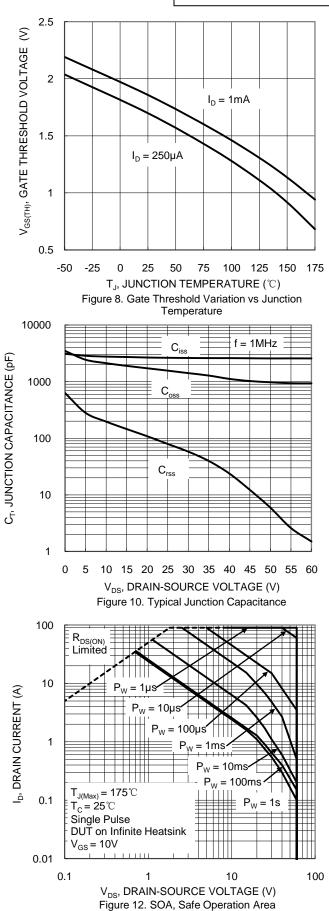
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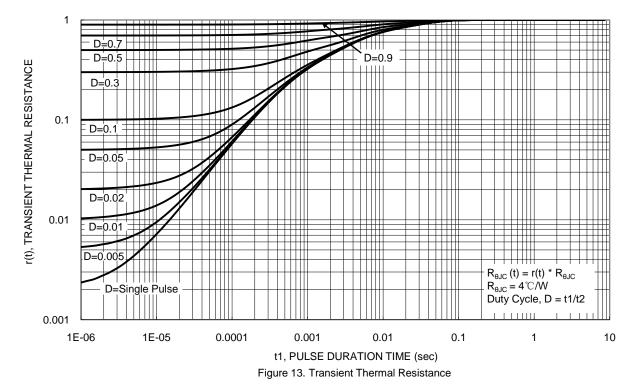


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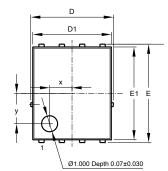


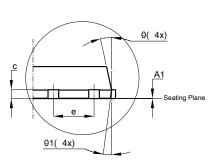


Package Outline Dimensions

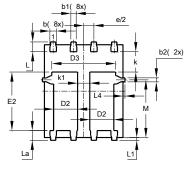
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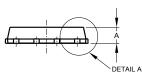
PowerDI5060-8 (Type C)







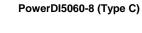


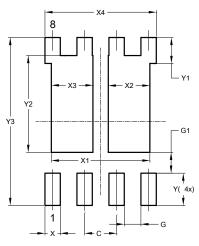


PowerDI5060-8 (Type C)						
			Тур			
Α	0.90	1.10	1.00			
A1	0	0.05	0.02			
b	0.33	0.51	0.41			
b1	0.300	0.366	0.333			
b2	0.20	0.35	0.25			
С	0.23	0.33	0.277			
D	5	.15 BS(0			
D1	4.85	4.95	4.90			
D2	1.40	1.60	1.50			
D3	-	-	3.98			
Е	6	.15 BS0	2			
E1	5.75	5.85	5.80			
E2	3.56	3.76	3.66			
е	1	.27BSC				
k	-	-	1.27			
k1	0.56	-	-			
L	0.51	0.71	0.61			
La	0.51	0.71	0.61			
L1	0.05	0.20	0.175			
L4	-	-	0.125			
М	3.50	3.71	3.605			
х	-	-	1.400			
У	-	-	1.900			
θ	10°	12°	11°			
θ1	6°	8°	7°			
All	All Dimensions in m					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	3.910		
X2	1.650		
X3	1.650		
X4	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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